

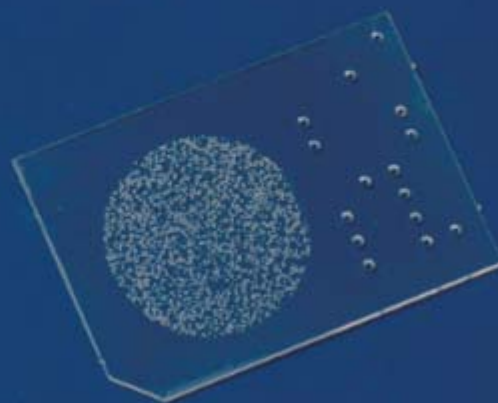
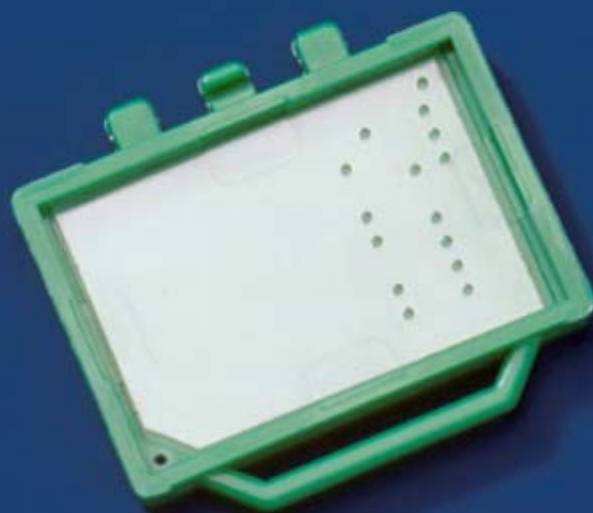
Response of a PADC Neutron Personal Dosemeter to HZE: ICCHIBAN-4 Results

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National Radiological Protection Board



Personal neutron dosimeters of simple design, processed using simple techniques developed for personal dosimetry, may be used to estimate this neutron component. Electrochemically etched pits in poly allyl diglycol carbonate (PADC or CR-39®) etched track detectors are identified and counted using fully automated read-out procedures.



The tracks observed will be produced not only by secondary charged particles from interactions of the neutron component of the radiation field, but also in part by the proton and energetic heavy charged particle components of the radiation field at the location of the dosimeter, leading to an over-estimate of the neutron component. The efficiency of the etch and read procedures is very dependent on particle type, energy and angle of incidence.

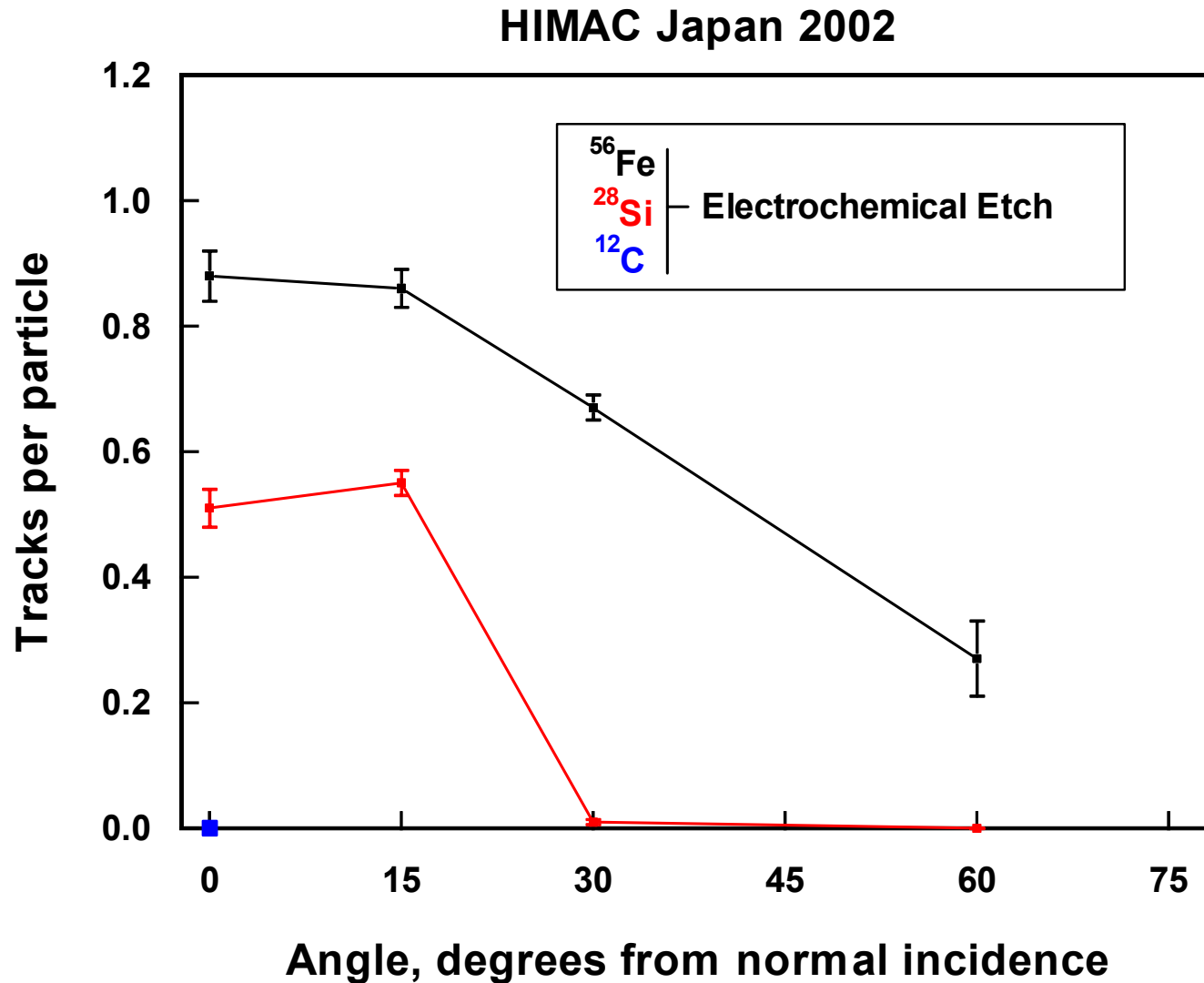
For the etch regime employed, the combination of high LET threshold (there is little response below a restricted LET_{200} in PADC of about $30 \text{ keV } \mu\text{m}^{-1}$), and poor angle dependence of response to high-energy charged particles (HZE), results in a much reduced overall response of the neutron dosimeter to the HZE component of the field in spacecraft and no response to protons of energy greater than about 1 MeV at the surface to be etched.

Preliminary measurements indicate that for examples of the HZE component of the radiation fields in spacecraft, a correction of 5 to 10% is necessary to account for the detector HZE response.

Alternatively, an additional chemical etch can be carried out which allows discrimination.

- PADC neutron personal dosimeter responds to neutrons plus neutron-like interactions of high-energy protons
- Only responds directly to protons of $E_p < \text{about } 1 \text{ MeV}$
- Some response to heavier charged particles
 $\text{LET}_{200} > \text{about } 30 \text{ keV } \mu\text{m}^{-1}$, depending on particle type
- Can generally distinguish HZE electrochemically etched tracks by second chemical etch

Figure showing results for ICCHIBAN-2



Charged particle angle dependence of relative response: ICCHIBAN-2 data

	0°	15°	30°	60°	75°	Forward 2 π (ISO free air)	ISO on body
⁵⁶ Fe 464 MeV/n	0.90	0.85	0.70	0.30	0	30% to 40%	15% to 20%
²⁸ Si 469 MeV/n	0.50	0.55	0.02	0	0	about 5%	about 2%

Results of ICCHIBAN-4 Irradiations

Measurements at HIMAC/ICCHIBAN-4 with the NRPB PADC Dosemeter



Electrochemical etch - back face

11.5 hours 20% NaOH at 40°C followed contiguously
by 8 hours 20% NaOH at 40°C at 23.5 kVcm⁻¹

Chemical etch - both faces

18 hours 20% NaOH at 80°C –only ECE results available at
present time

Electrochemical etching- single detector charged particle results: ^{12}C 400 MeV/n

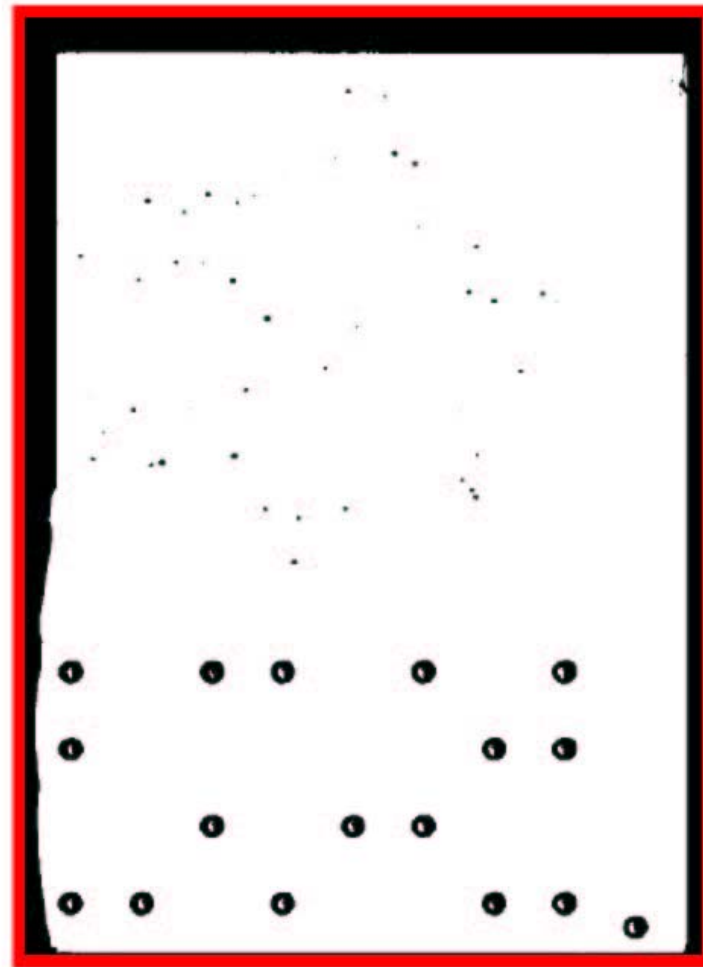
Particle/ Energy	Shielding condition	LET keV μm^{-1}	Dose mGy	Fluence cm^{-2}	Corrected Net Tracks ^(a) cm^{-2}		Note
					Det.1	Det.2	
^{12}C 400 MeV/n	zero	10.963	1	57000	8	1	(b)
	5 g cm^{-2} Al	?		?	9	11	(c)
	10 g cm^{-2} Al	?		?	21	14	(d)
	5 g cm^{-2} PMMA	?		?	19	15	(e)

(a) Observed number of tracks cm^{-2} after subtraction of background and corrected for non-linearity at high track density

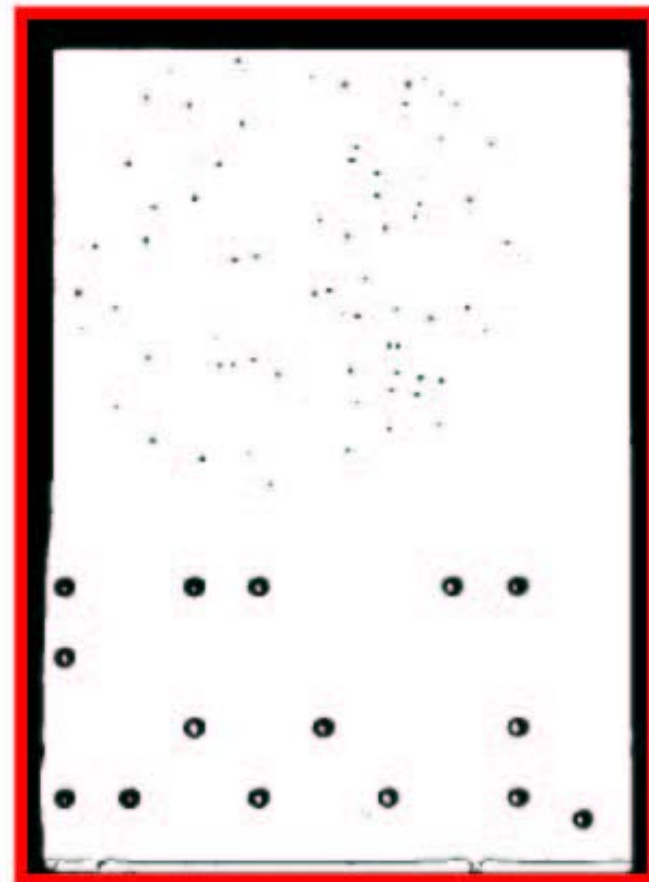
(b) Not significantly different from background. Primary beam particles below LET threshold

(c), (d), (e) Primary beam particles below LET threshold. A few higher LET fragments? - some larger tracks

In subsequent figures, detector 1 is edged in orange, detector 2 in red.



C pack 1		1mGy	
Condition		mono	
ID	Dtr	Tracks	Net Corr Tracks
24	D109235	41	15
41	D109205	28	2



C pack 2
Condition

1mGy
5g Al

ID

Dtr

Tracks

Net Corr Tracks

6

D109239

42

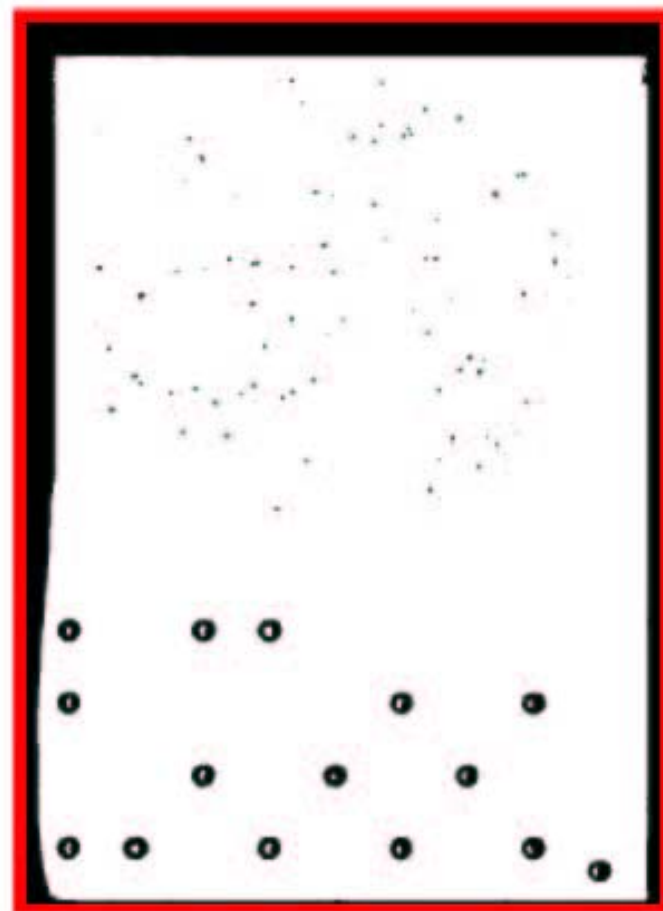
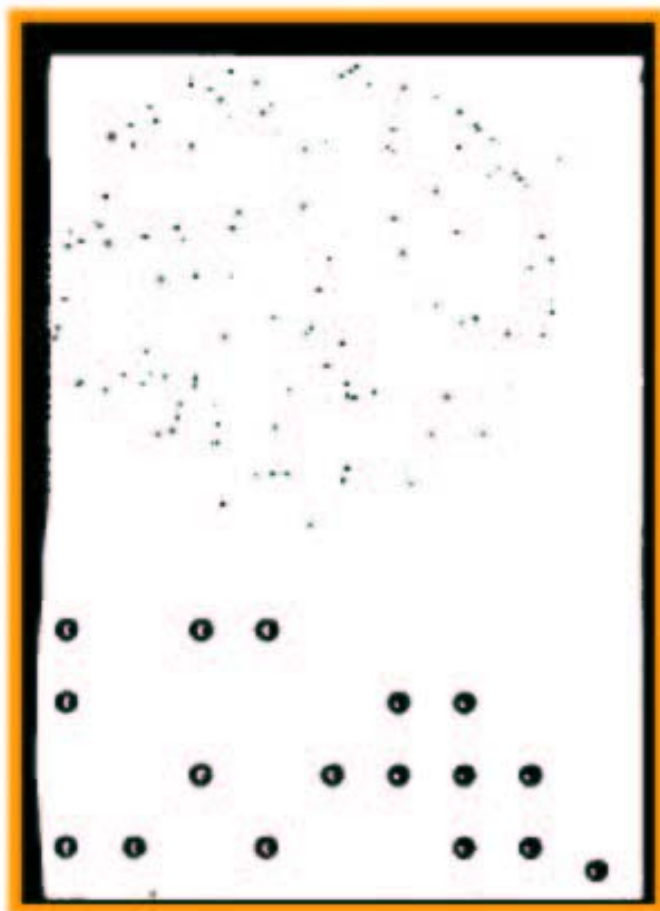
16

35

D109218

46

20



C pack 3
Condition

1mGy
10g Al

ID

Dtr

Tracks

Net Corr Tracks

21

D109267

63

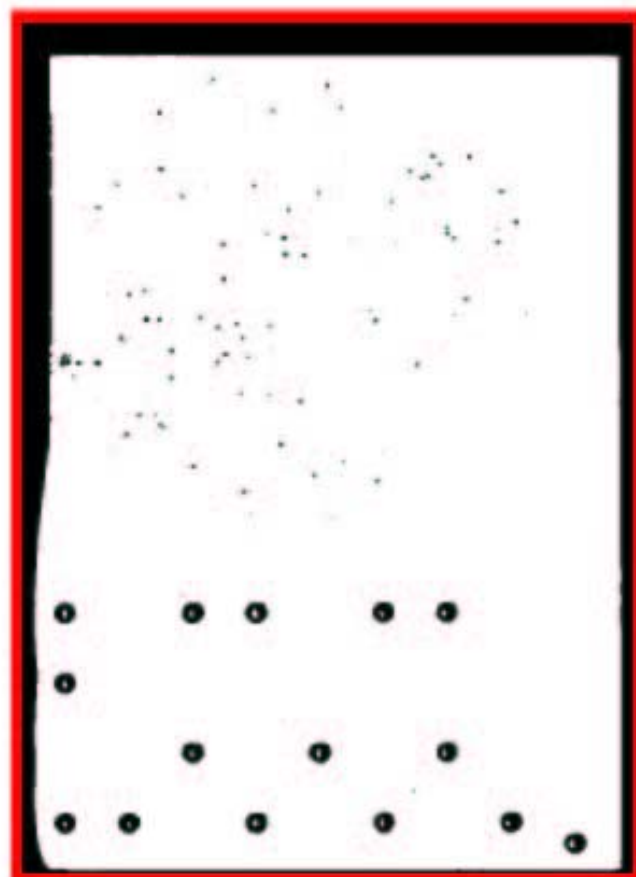
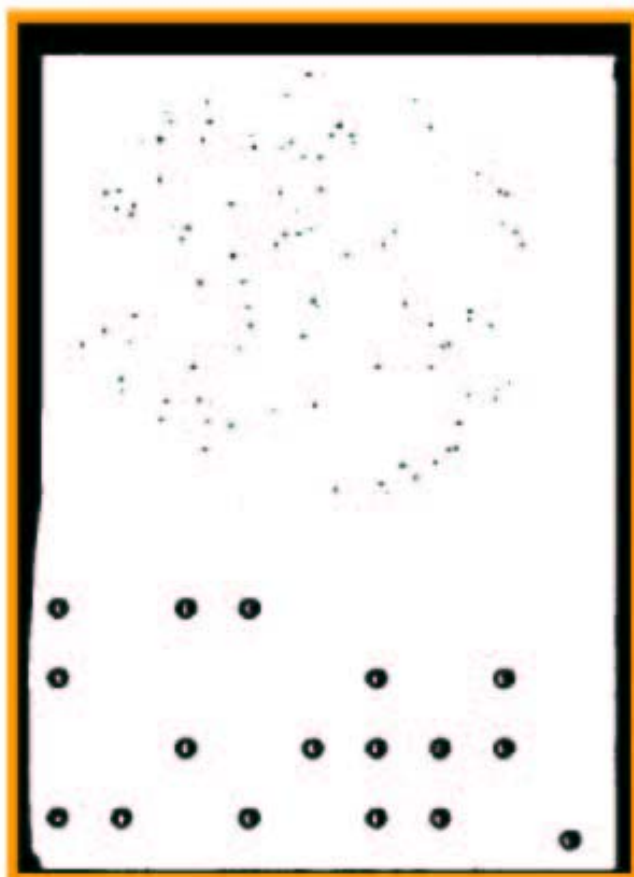
37

40

D109252

50

24



C pack 4
Condition

1mGy
5g H₂O

ID

Dtr

Tracks

Net Corr Tracks

1

D109273

59

33

34

D109290

52

26

Electrochemical etching- single detector

charged particle results: ^{20}Ne 400 MeV/n

Particle/ Energy	Shielding condition	LET keV μm^{-1}	Dose mGy	Fluence cm^{-2}	Corrected Net Tracks ^(a) cm^{-2}		Note
					Det.1	Det.2	
^{20}Ne 400 MeV/n	zero	30.959	1	20200	690	23	(f)
	5 g cm^{-2} Al	?		?	225	1180	(g)
	10 g cm^{-2} Al	?		?	8390	5520	(h)
	5 g cm^{-2} PMMA	?		?	5000	7020	(i)

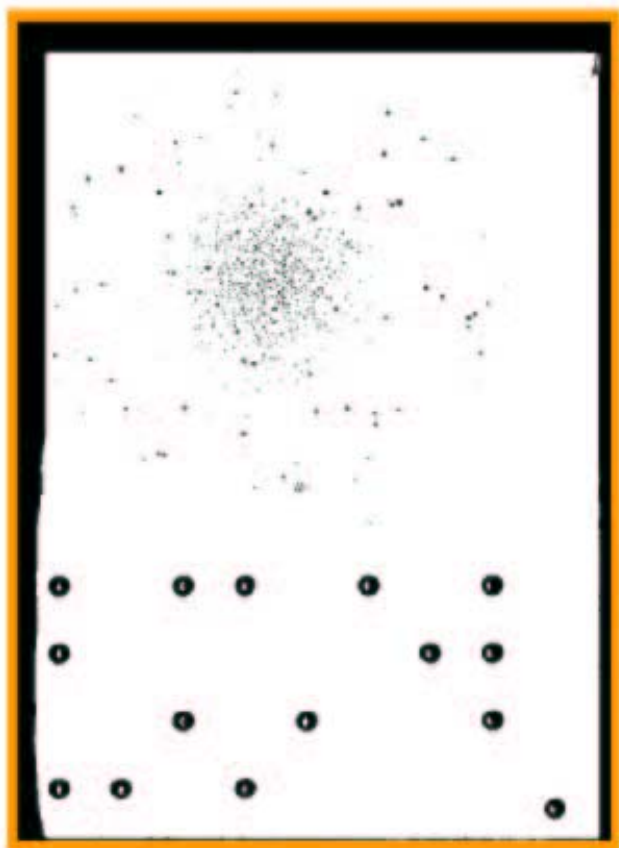
(f), (g) At LET threshold – some non-uniformity of response across/between detectors because of small

differences in applied field strength during processing

(h), (i) Just on LET threshold – some non-uniformity of response

In subsequent figures, detector 1 is edged in orange, detector 2 in red

482 microns



520 microns



Ne pack 1
Condition

1mGy
mono

ID
33
71

Dtr

D109284

D109201

Tracks

1105

66

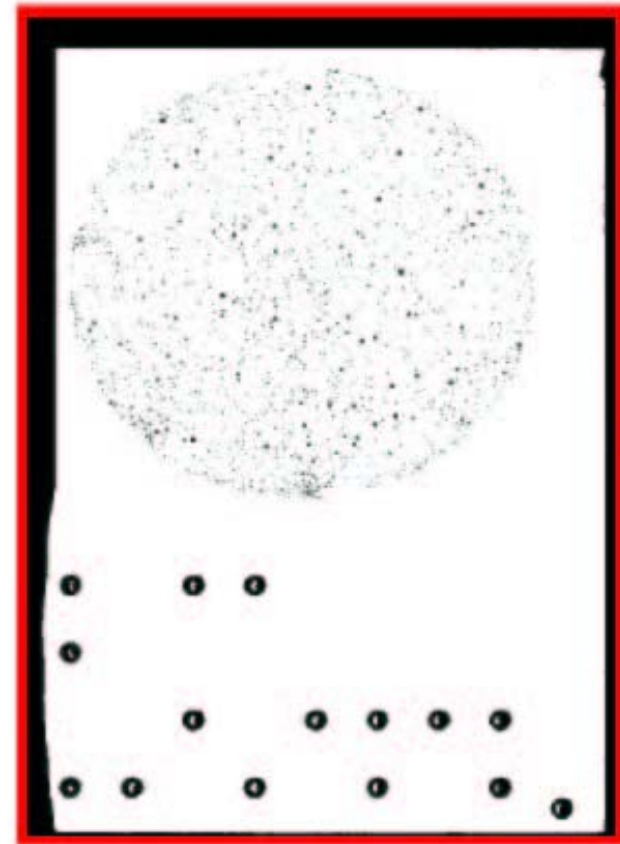
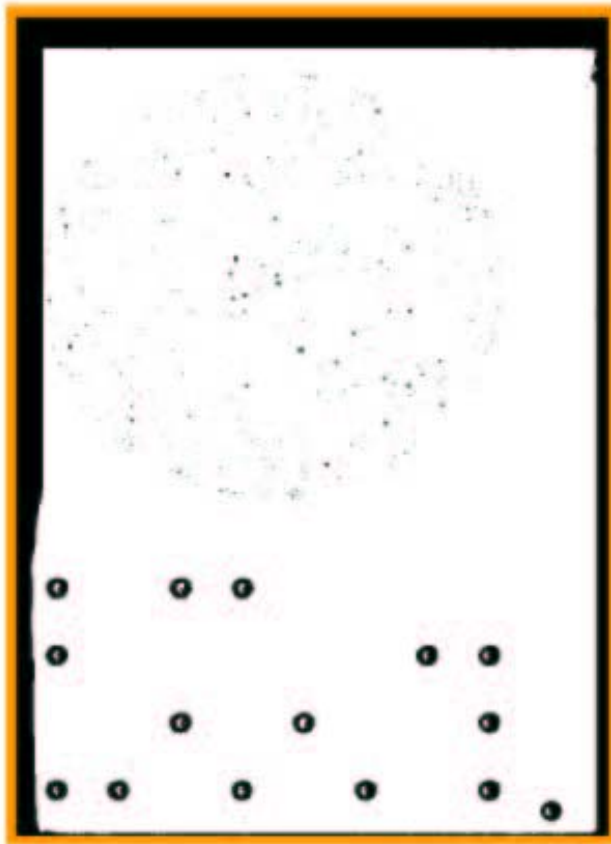
Net Corr Tracks

1220

40

513 microns

502 microns



Ne pack 2
Condition

1mGy
5g Al

ID
59
64

Dtr

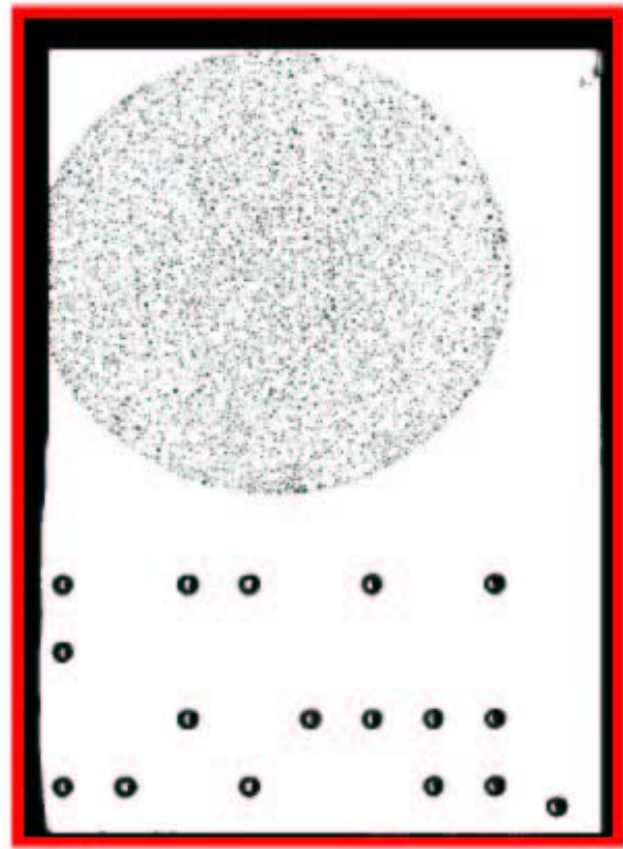
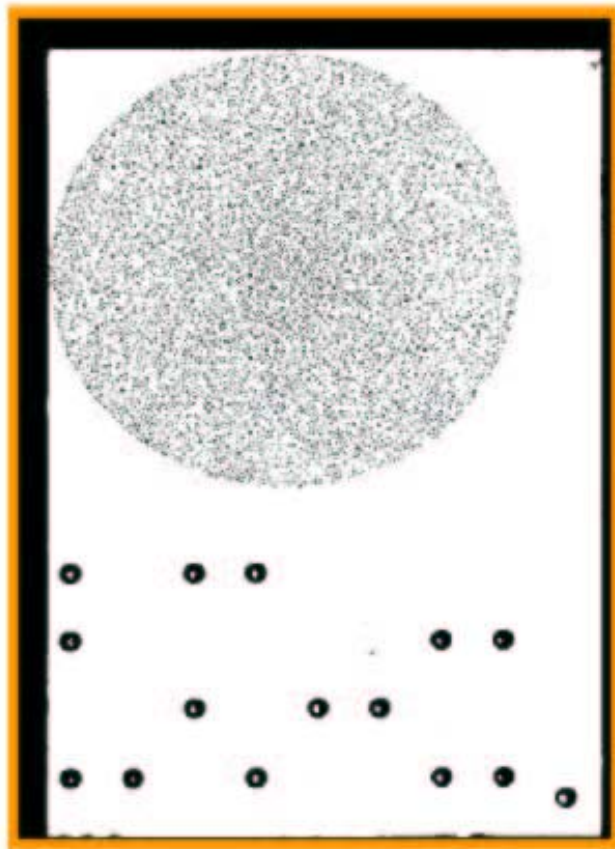
D109214
D109232

Tracks
406
1744

Net Corr Tracks
397
2093

506 microns

516 microns



Ne pack 3
Condition

1mGy
10g Al

ID
13
54

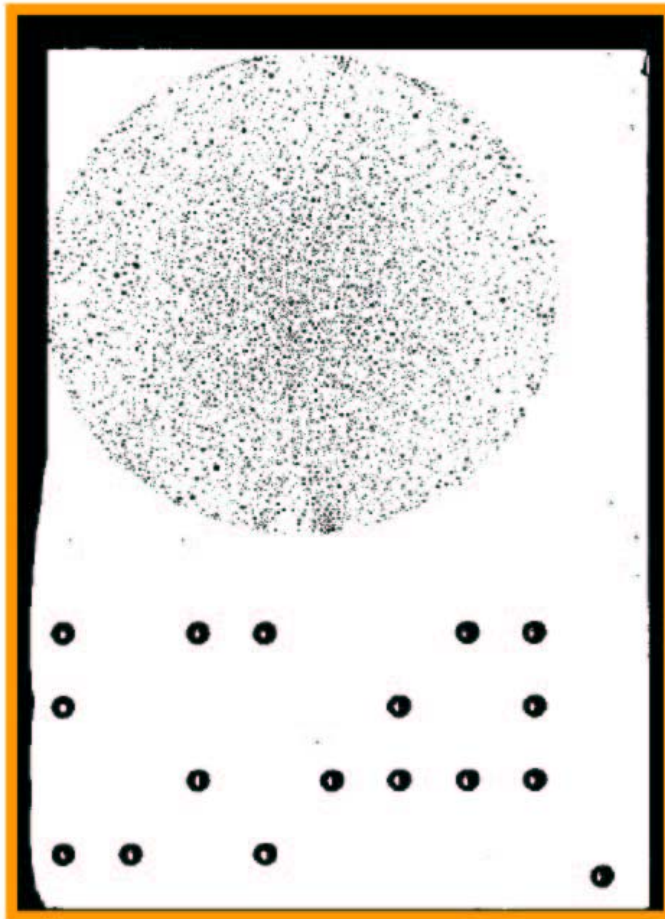
Dtr

D109225
D109203

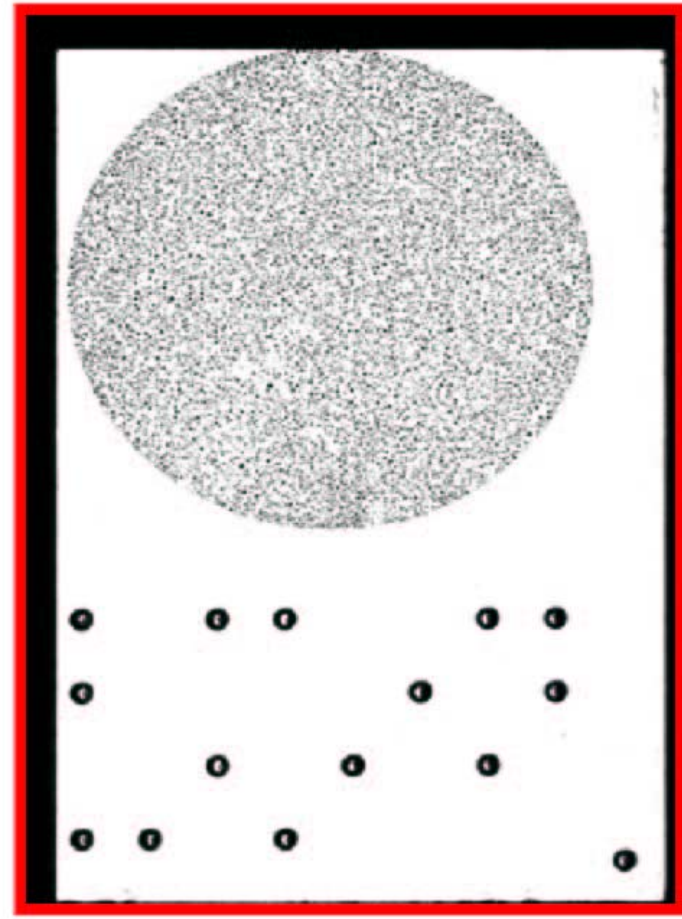
Tracks
6704
5250

Net Corr Tracks
14818
9750

485 microns



500 microns



Ne pack 4
Condition

1mGy
5g H₂O

ID
37
52

Dtr
D109260
D109240

Tracks
4943
6057

Net Corr Tracks
8841
12400

Electrochemical etching- single detector charged

particle results: ^{56}Fe 500 MeV/n

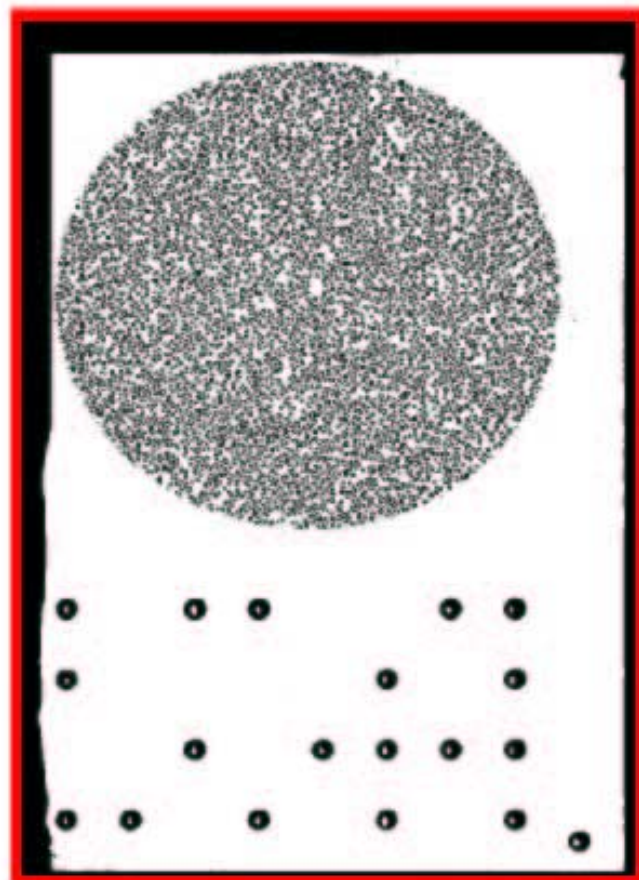
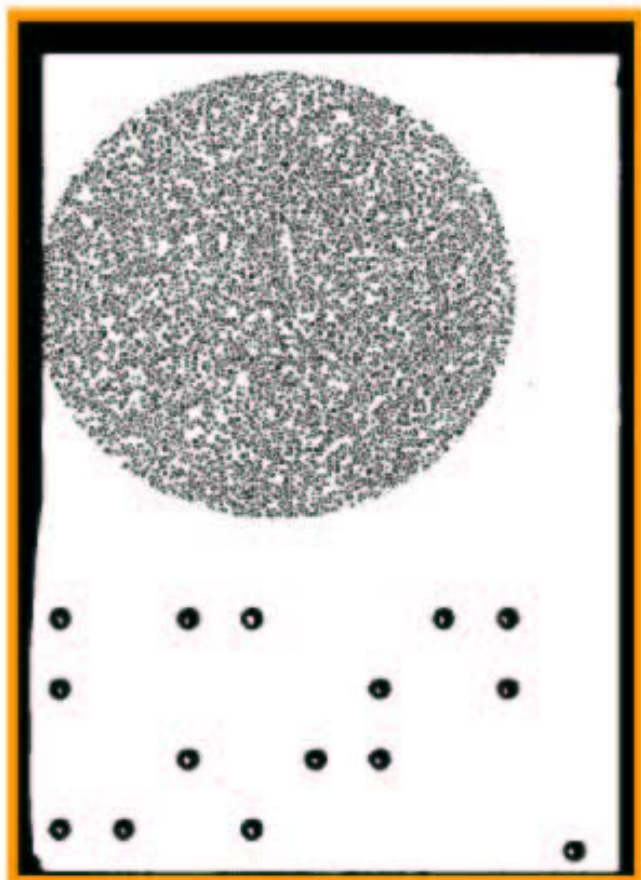
Particle/ Energy	Shielding condition	LET keV μm^{-1}	Dose mGy	Fluence cm^{-2}	Corrected Net Tracks ^(a) cm^{-2}		Note
					Det.1	Det.2	
^{56}Fe 500 MeV/n	zero	~ 190	1	~ 3300	3980	3790	(j)
	5 g cm^{-2} Al	?		?	3420	3440	(k)
	10 g cm^{-2} Al	?		?	380	360	(l)
	5 g cm^{-2} PMMA	?		?	3640	3570	(m)

(j), (k) Above threshold, 100% detection efficiency

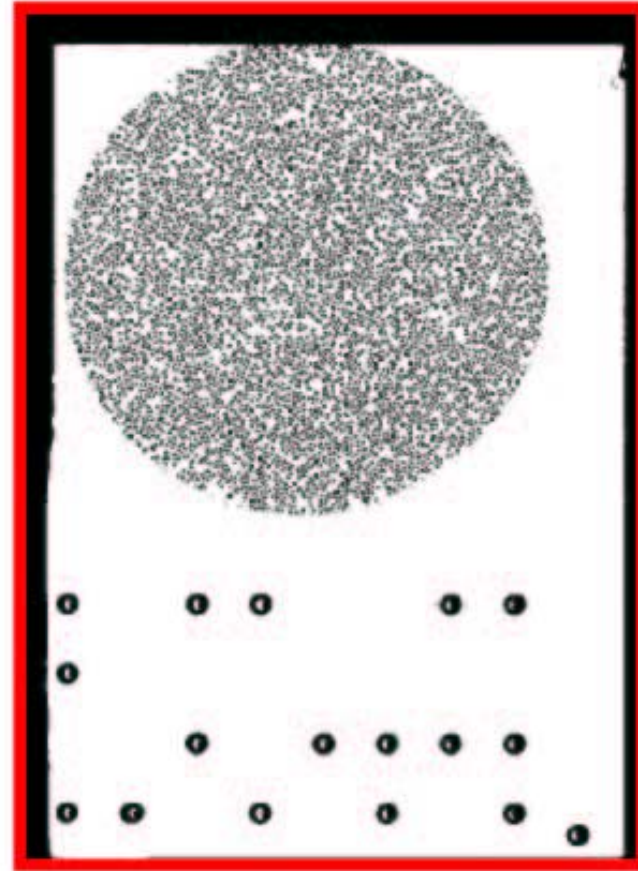
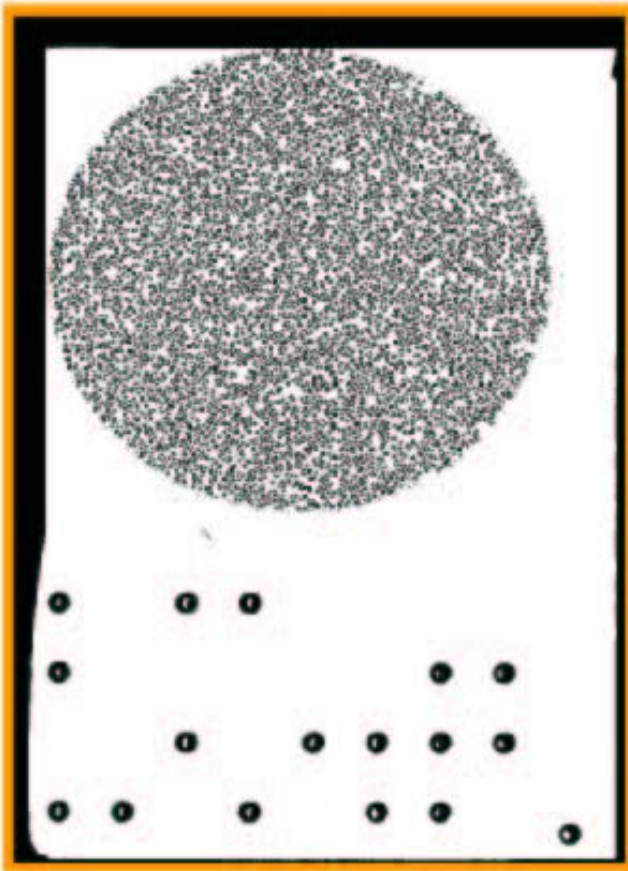
(l) Beyond Bragg peak- some fragments plus a few secondary neutrons?

(m) Above threshold, 100% detection efficiency

In subsequent figures, detector 1 is edged in orange, detector 2 in red



Fe pack 1		ImGy	
Condition		mono	
ID	Dtr	Tracks	Net Corr Tracks
16	D109268	4271	7032
72	D109270	4138	6702



Fe pack 2
Condition

1mGy
5g Al

ID
30
58

Dtr

D109237

D109230

Tracks

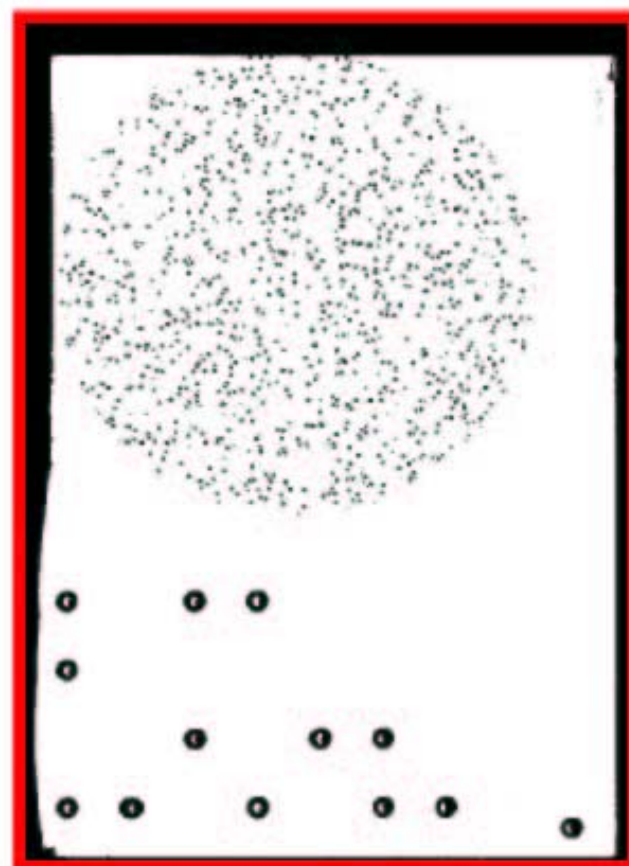
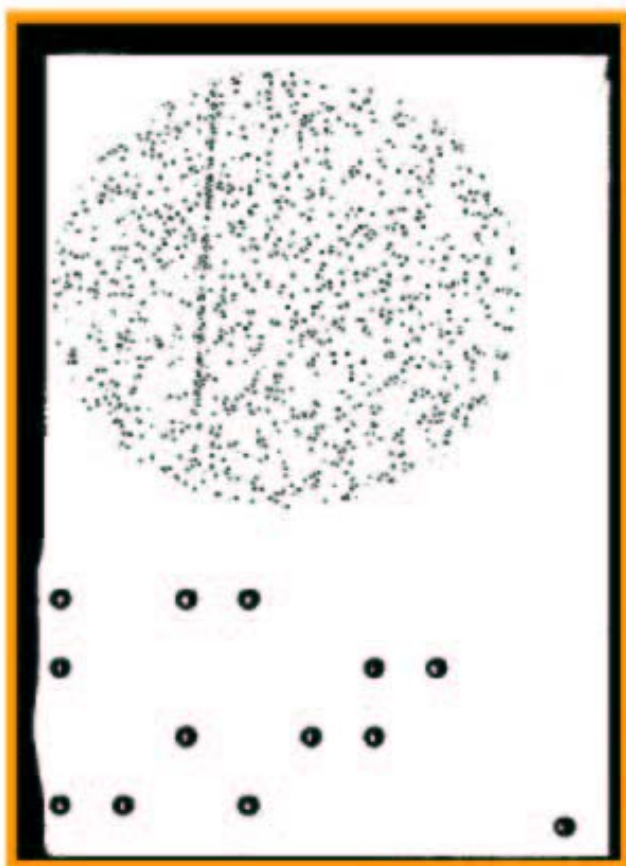
3864

3878

Net Corr Tracks

6048

6081



Fe pack 3

1mGy

Condition

10g Al

ID

Dtr

Tracks

Net Corr Tracks

4

D109264

656

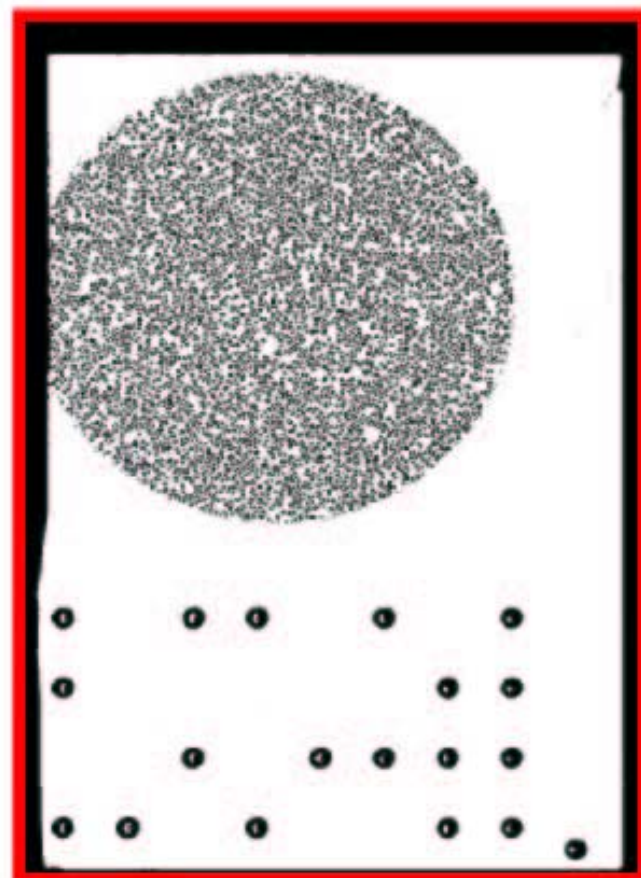
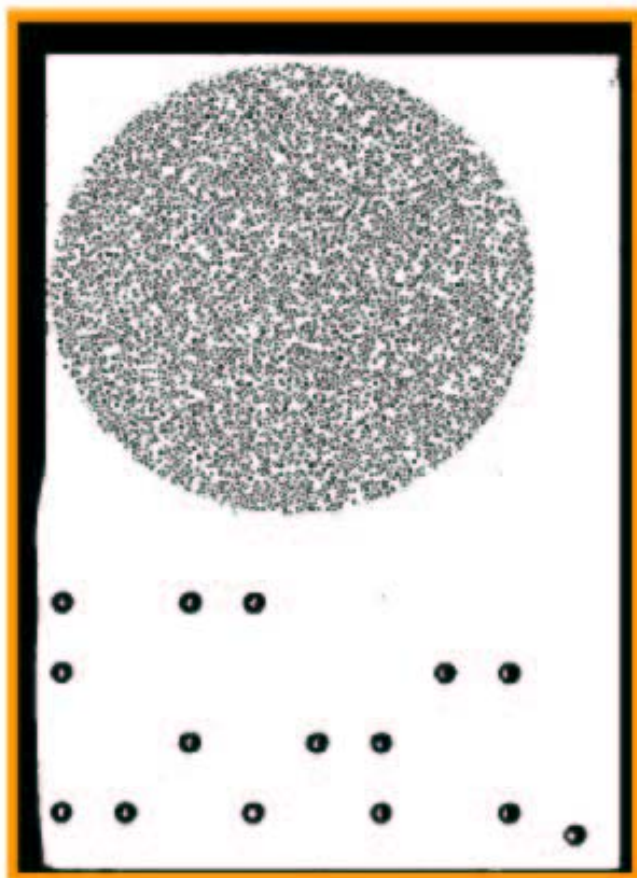
677

36

D109231

621

637



Fe pack 4
Condition

1mGy
5g H₂O

ID
39
61

Dtr
D109234
D109207

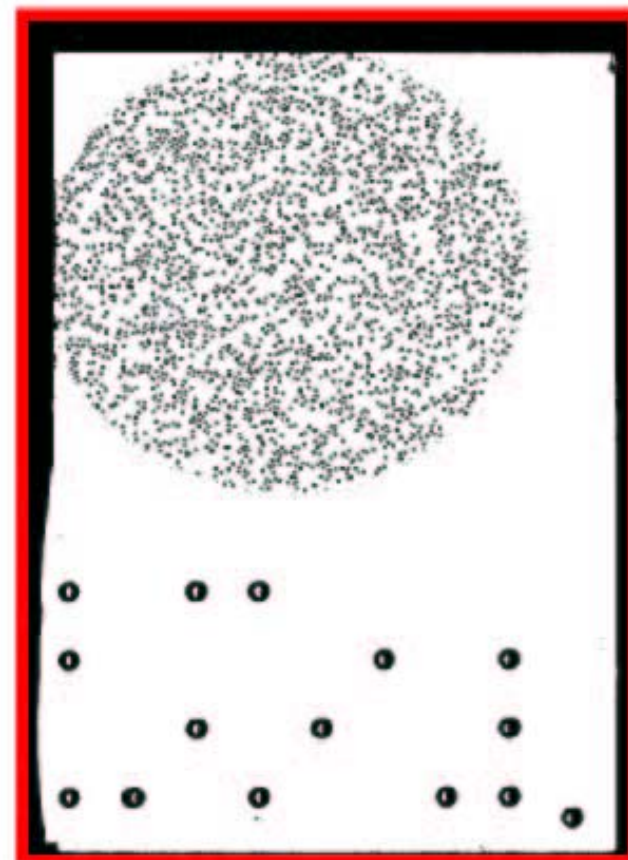
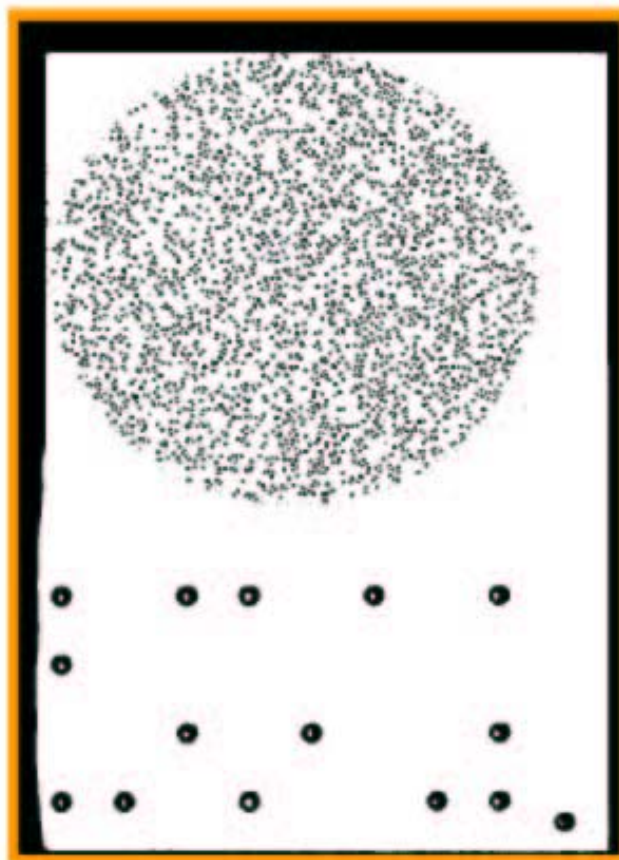
Tracks
4029
3974

Net Corr Tracks
6438
6306

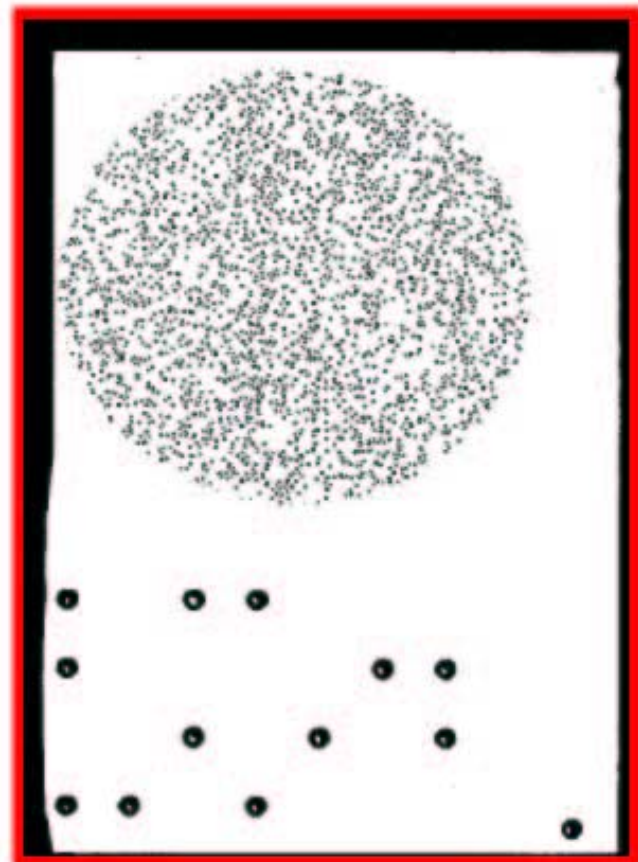
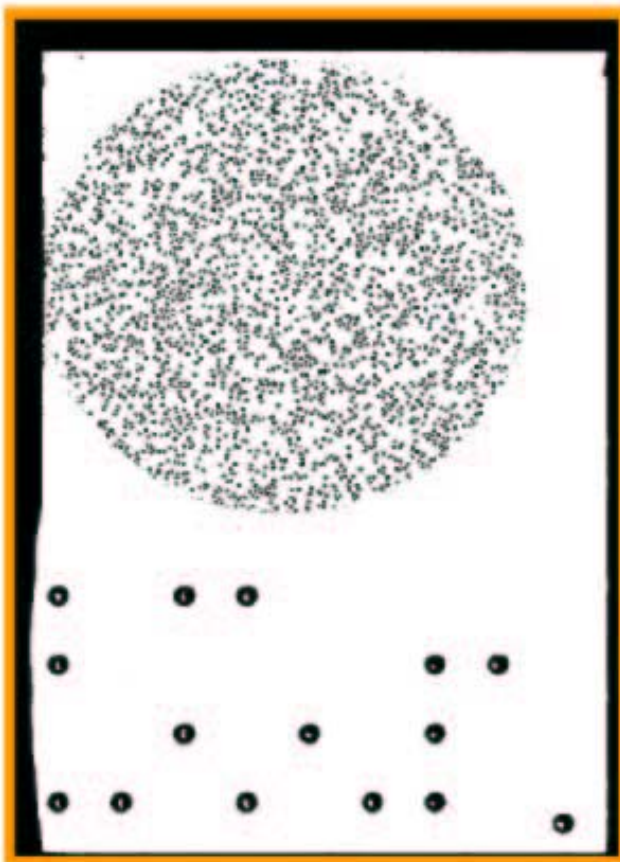
Electrochemical etching- single detector charged particle results: 'blind' irradiations

Particle/ Energy	Shielding condition	LET keV μm^{-1}	Dose mGy	Fluence cm^{-2}	Corrected Net Tracks ^(a) cm^{-2}		Note
					Det.1	Det.2	
'Blind' 4	?	?	?	?	1040	990	
'Blind' 6	?	?	?	?	1040	1080	
'Blind' 7	?	?	?	?	3460	3580	

In subsequent figures, detector 1 is edged in orange, detector 2 in red



Blind Pack 1		Blind 4	
Condition		Dtr	
ID			Tracks
9		D109281	1565
48		D109241	1506
			Net Corr Tracks
			1836
			1753



Blind Pack 2

Condition

Blind 6

ID

Dtr

Tracks

Net Corr Tracks

20

D109217

1566

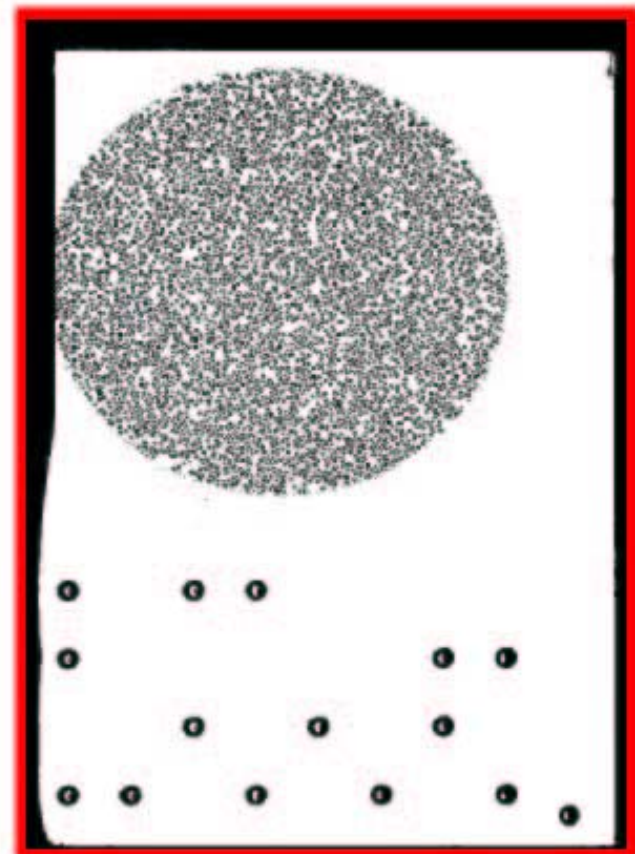
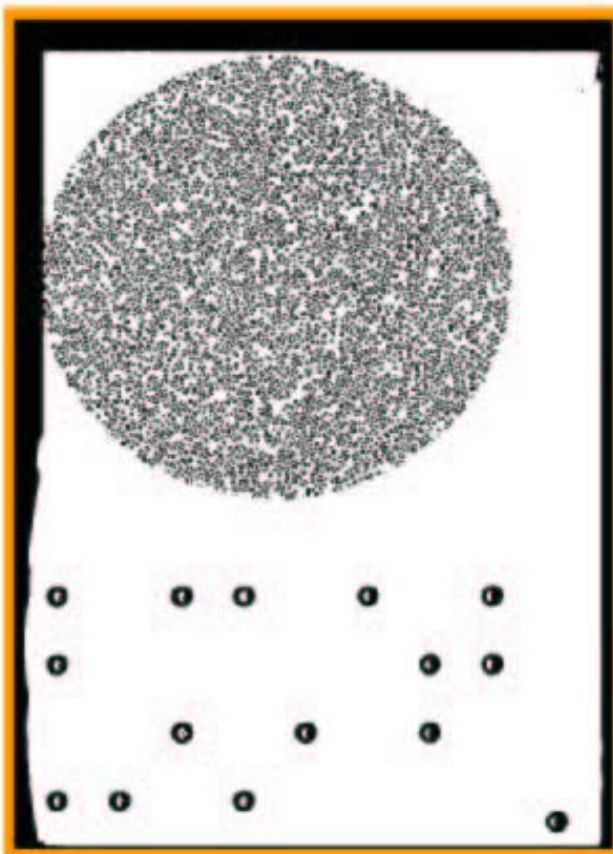
1837

56

D109246

1617

1909



Blind Pack 3

Condition

Blind 7

ID

Dtr

Tracks

Net Corr Tracks

10

D109286

3892

6114

77

D109216

3980

6321

Electrochemical etching- single detector charged particle full results

Particle/ Energy	Shielding condition	LET keV μm^{-1}	Dose mGy	Fluence cm^{-2}	Corrected Net Tracks ^(a) cm^{-2}	
^{12}C 400 MeV/n	zero	10.963	1	57000	8	1
	5 g cm^{-2} Al	?		?	9	11
	10 g cm^{-2} Al	?		?	21	14
	5 g cm^{-2} PMMA	?		?	19	15
^{20}Ne 400 MeV/n	zero	30.959	1	20200	690	23
	5 g cm^{-2} Al	?		?	225	1180
	10 g cm^{-2} Al	?		?	8390	5520
	5 g cm^{-2} PMMA	?		?	5000	7020
^{56}Fe 500 MeV/n	zero	~ 190	1	~3300	3980	3790
	5 g cm^{-2} Al	?		?	3420	3440
	10 g cm^{-2} Al	?		?	380	360
	5 g cm^{-2} PMMA	?		?	3640	3570
‘Blind’ 4		?	?	?	1040	990
‘Blind’ 6		?	?	?	1040	1080
‘Blind’ 7		?	?	?	3460	3580

ACKNOWLEDGEMENTS

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